

# Dual High-Speed 1.5A MOSFET Drivers

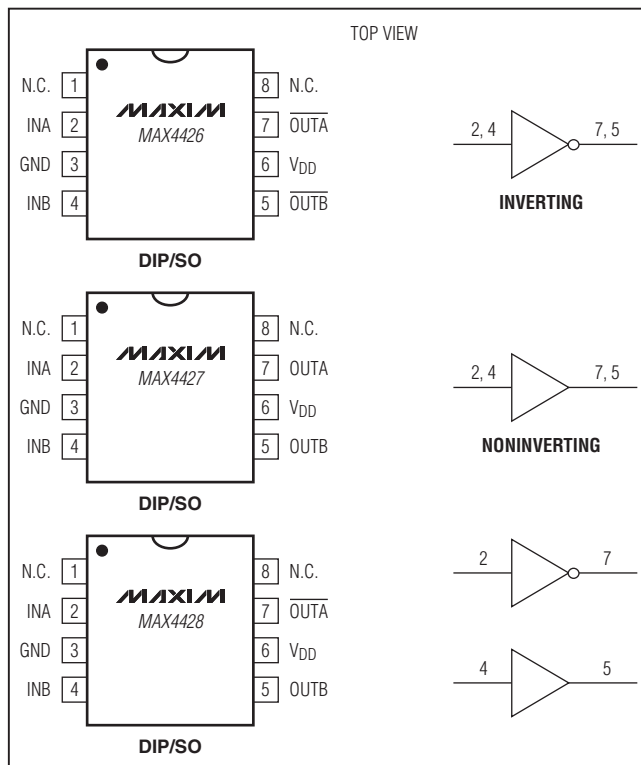
## General Description

The MAX4426/MAX4427/MAX4428 are dual monolithic MOSFET drivers designed to translate TTL/CMOS inputs to high voltage/current outputs. The MAX4426 is a dual inverting power MOSFET driver. The MAX4427 is a dual noninverting power MOSFET driver, and the MAX4428 contains one inverting section and one noninverting section. Delay times are nearly independent of  $V_{DD}$  (see *Typical Operating Characteristics*). High-current output drivers rapidly charge and discharge the gate capacitance of even the largest power MOSFETs to within millivolts of the supply rails. This produces the power MOSFETs' minimum on resistance. The MAX4426/MAX4427/MAX4428's high speed minimizes power losses in switching power supplies and DC-DC converters.

## Applications

Switching Power Supplies  
DC-DC Converters  
Motor Controllers  
Pin-Diode Drivers  
Charge-Pump Voltage Inverters

## Pin Configurations



## Features

- ◆ Upgrade for TSC4426/TSC4427/TSC4428
- ◆ Lower On Resistance: 4Ω vs. 7Ω
- ◆ Shorter Delay Times:  $t_{D1}$  - 10ns vs. 30ns  
 $t_{D2}$  - 25ns vs. 50ns
- ◆ 1.5A Peak Output Current
- ◆ Fast Rise and Fall Times: Typically 20ns with 1000pF Load
- ◆ Wide Operating Range: 4.5V to 18V
- ◆ Low Power Consumption: 1.8mA with Logic 1 Input  
200μA with Logic 0 Input
- ◆ TTL/CMOS Compatible
- ◆ Latchup Protected-Withstand > 500mA Reverse Current
- ◆ ESD Protected

## Ordering Information

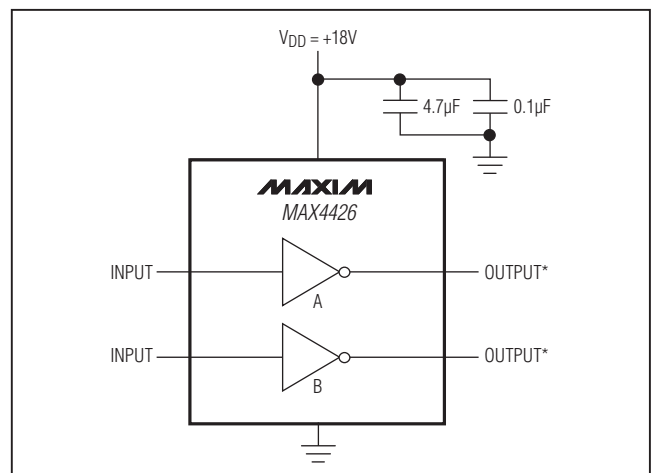
| PART       | TEMP RANGE      | PIN-PACKAGE   |
|------------|-----------------|---------------|
| MAX4426CPA | 0°C to +70°C    | 8 Plastic DIP |
| MAX4426CSA | 0°C to +70°C    | 8 SO          |
| MAX4426C/D | 0°C to +70°C    | Dice*         |
| MAX4426EPA | -40°C to +85°C  | 8 Plastic DIP |
| MAX4426ESA | -40°C to +85°C  | 8 SO          |
| MAX4426EJA | -40°C to +85°C  | 8 CERDIP      |
| MAX4426MJA | -55°C to +125°C | 8 CERDIP**    |

Ordering Information continued on end of data sheet.

\*Dice are tested at  $T_A = +25^\circ\text{C}$ .

\*\*Contact factory for availability and processing to MIL-STD-883.

## Typical Operating Circuit



# Dual High-Speed 1.5A MOSFET Drivers

## ABSOLUTE MAXIMUM RATINGS

Supply Voltage  $V_{DD}$  to GND ..... +20V  
 Time  $V_{IL} < V_{IN} < V_{IH}$  ..... 50ns  
 Input Voltage .....  $V_{DD} + 0.3V$  to GND - 0.3V  
 Continuous Power Dissipation ( $T_A = +70^\circ\text{C}$ )  
     Plastic DIP (derate 9.09mW/ $^\circ\text{C}$  above  $+70^\circ\text{C}$ ) ..... 727mW  
     SO (derate 5.88mW/ $^\circ\text{C}$  above  $+70^\circ\text{C}$ ) ..... 471mW  
     CERDIP (derate 8.00mW/ $^\circ\text{C}$  above  $+70^\circ\text{C}$ ) ..... 640mW

Operating Temperature Ranges:  
 MAX442\_C\_ .....  $0^\circ\text{C}$  to  $+70^\circ\text{C}$   
 MAX442\_E\_ .....  $-40^\circ\text{C}$  to  $+85^\circ\text{C}$   
 MAX442\_MJA .....  $-55^\circ\text{C}$  to  $+125^\circ\text{C}$   
 Storage Temperature Range .....  $-55^\circ\text{C}$  to  $+160^\circ\text{C}$   
 Maximum Chip Temperature .....  $+150^\circ\text{C}$   
 Lead Temperature (soldering, 10 sec) .....  $+300^\circ\text{C}$

*Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.*

## ELECTRICAL CHARACTERISTICS

( $V_{DD} = +4.5V$  to  $+18V$ ,  $T_A = T_{MIN}$  to  $T_{MAX}$ , unless otherwise specified.)

| PARAMETER             | SYMBOL     | CONDITIONS                            |  | MIN                          | TYP | MAX | UNITS         |
|-----------------------|------------|---------------------------------------|--|------------------------------|-----|-----|---------------|
| Logic 1 Input Voltage | $V_{IH}$   |                                       |  | 2.4                          |     |     | V             |
| Logic 0 Input Voltage | $V_{IL}$   |                                       |  |                              |     | 0.8 | V             |
| Input Current         | $I_{IN}$   | $V_{IN} = 0V$ to $18V$                |  | -1                           |     | 1   | $\mu\text{A}$ |
| Output High Voltage   | $V_{OH}$   | No load                               |  | $V_{DD} - 25$                |     |     | mV            |
| Output Low Voltage    | $V_{OL}$   | No load                               |  |                              |     | 25  | mV            |
| Output Resistance     | $R_{OUT}$  | $V_{DD} = 18V$ ,<br>$I_{LOAD} = 10mA$ | $V_{IN} = 0.8V$ for inverting stages,<br>$V_{IN} = 2.4V$ for noninverting stages | $T_A = +25^\circ\text{C}$    | 4   | 10  | $\Omega$      |
|                       |            |                                       |  | $T_A = T_{MIN}$ to $T_{MAX}$ | 5   | 12  |               |
|                       |            |                                       | $V_{IN} = 2.4V$ for inverting stages,<br>$V_{IN} = 0.8V$ for noninverting stages | $T_A = +25^\circ\text{C}$    | 4   | 10  |               |
|                       |            |                                       |  | $T_A = T_{MIN}$ to $T_{MAX}$ | 5   | 12  |               |
| Peak Output Current   | $I_{PK}$   | $V_{DD} = 18V$                        |  |                              | 1.5 |     | A             |
| Power-Supply Current  | $I_{SUPP}$ | $V_{IN} = +3V$ for both inputs        | $T_A = +25^\circ\text{C}$  | 1.8                          | 4.5 | mA  |               |
|                       |            |                                       | $T_A = T_{MIN}$ to $T_{MAX}$   | 2.5                          | 8.0 |     |               |
|                       |            | $V_{IN} = 0V$ for both inputs         | $T_A = +25^\circ\text{C}$  | 0.2                          | 0.4 |     |               |
|                       |            |                                       | $T_A = T_{MIN}$ to $T_{MAX}$   | 0.3                          | 0.6 |     |               |
| Rise Time (Note 1)    | $t_R$      | $T_A = +25^\circ\text{C}$             |  | 20                           | 30  | ns  |               |
|                       |            | $T_A = T_{MIN}$ to $T_{MAX}$          |  | 25                           | 40  |     |               |
| Fall Time (Note 1)    | $t_F$      | $T_A = +25^\circ\text{C}$             |  | 20                           | 30  | ns  |               |
|                       |            | $T_A = T_{MIN}$ to $T_{MAX}$          |  | 25                           | 40  |     |               |
| Delay Time (Note 1)   | $t_{D1}$   | $T_A = +25^\circ\text{C}$             |  | 10                           | 30  | ns  |               |
|                       |            | $T_A = T_{MIN}$ to $T_{MAX}$          |  | 15                           | 40  |     |               |
|                       | $t_{D2}$   | $T_A = +25^\circ\text{C}$             |  | 25                           | 50  | ns  |               |
|                       |            | $T_A = T_{MIN}$ to $T_{MAX}$          |  | 30                           | 60  |     |               |

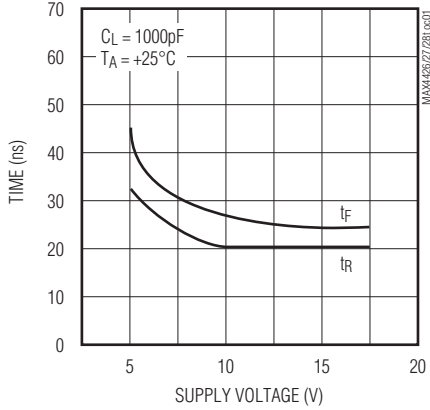
**Note 1:** Switching times guaranteed by design, not tested. See Figure 1 for timing measurement circuit.

# Dual High-Speed 1.5A MOSFET Drivers

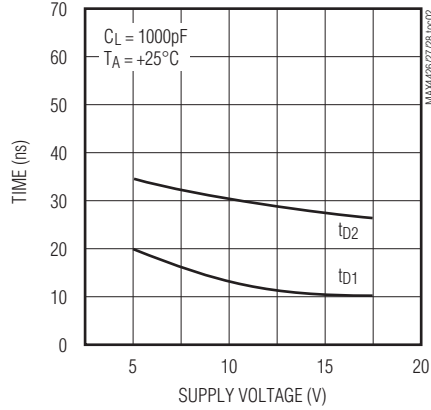
## Typical Operating Characteristics

MAX4426/MAX4427/MAX4428

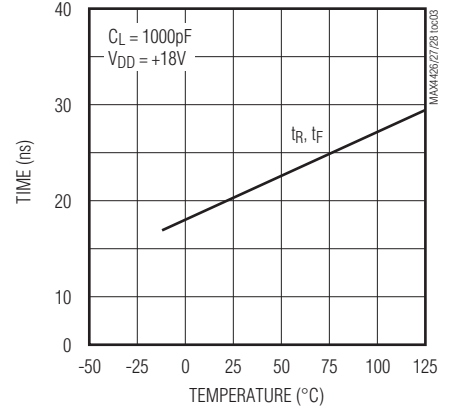
**MAX4426 RISE AND FALL TIME vs. SUPPLY VOLTAGE**



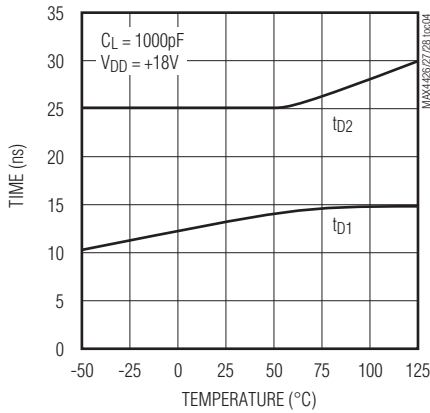
**MAX4426 DELAY TIME vs. SUPPLY VOLTAGE**



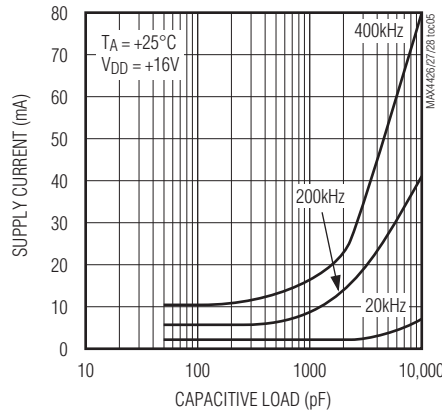
**MAX4426 RISE AND FALL TIME vs. TEMPERATURE**



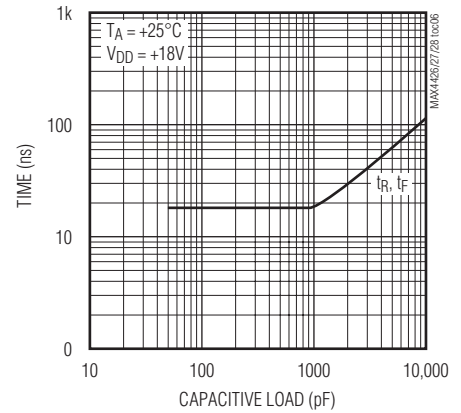
**MAX4426 DELAY TIME vs. TEMPERATURE**



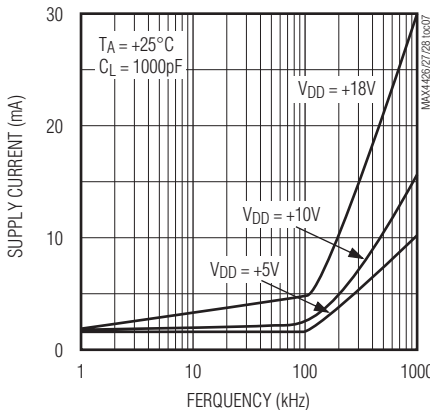
**MAX4426 SUPPLY CURRENT vs. CAPACITIVE LOAD**



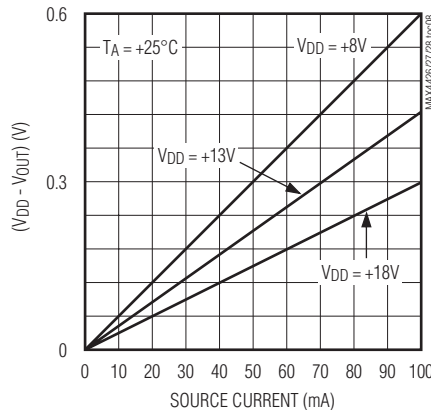
**MAX4426 RISE AND FALL TIME vs. CAPACITIVE LOAD**



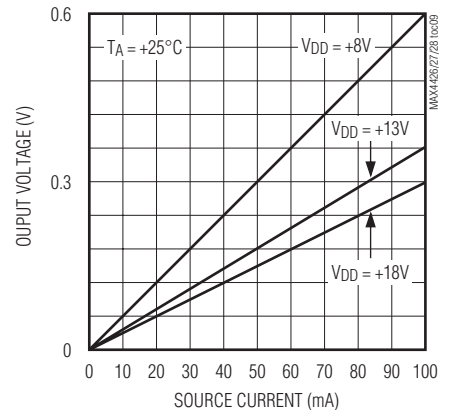
**MAX4426 SUPPLY CURRENT vs. FREQUENCY**



**MAX4426 OUTPUT HIGH VOLTAGE vs. SOURCE CURRENT**



**MAX4426 OUTPUT LOW VOLTAGE vs. SOURCE CURRENT**



# Dual High-Speed 1.5A MOSFET Drivers

## Applications Information

The MAX4426/MAX4427/MAX4428 have easy-to-drive inputs. However, these inputs must never be allowed to stay between  $V_{IH}$  and  $V_{IL}$  for more than 50ns. Unused inputs should always be connected to ground to minimize supply current. Drivers can be paralleled on the MAX4426 or MAX4427 by tying both Inputs together and both outputs together.

Supply bypassing and grounding are extremely important with the MAX4426/MAX4427/MAX4428, as the peak supply current can be as high as 3A, which is twice the peak output current. Ground drops are a form of negative feedback with inverters, and hence will degrade the delay and transition time of the MAX4426/MAX4428.

Suggested bypass capacitors are a 4.7 $\mu$ F (low ESR) capacitor in parallel with a 0.1 $\mu$ F ceramic capacitor, mounted as close as possible to the MAX4426/MAX4427/MAX4428. Use a ground plane if possible or separate ground returns for inputs and outputs. Output voltage ringing can be minimized with a 5 $\Omega$  to 20 $\Omega$  resistor in series with the output, but this will degrade output transition time. Ringing may be undesirable due to the large current that flows through capacitive loads when the voltage across these loads transitions quickly.

Operation at the upper end of the supply voltage range (> 15V) requires that a capacitance of at least 50pF be present at the outputs. This prevents the supply voltage provided to the die (which can be different from that seen at the supply pin) from exceeding the 20V absolute maximum rating, due to overshoot. Since at least 50pF of gate capacitance is present in all higher power FETs, this requirement is easily met.

## Power Dissipation

The MAX4426/MAX4427/MAX4428 power dissipation consists of input inverter losses, crowbar current through the output devices, and output current (either capacitive or resistive). The sum of these must be kept below the maximum power dissipation limit.

The DC input inverter supply current is 0.2mA when both inputs are low and 2mA when both inputs are high. The crowbar current through an output device making a transition is approximately 100mA for a few nanoseconds. This is a small portion of the total supply current, except for high switching frequencies or a small load capacitance (100pF).

The MAX4426/MAX4427/MAX4428 power dissipation when driving a ground-referenced resistive load is:

$$P = (D) (r_{ON(MAX)}) (I_{LOAD})^2$$

where D is the percentage of time the MAX4426/MAX4427/MAX4428 output pulls high,  $r_{ON(MAX)}$  is the MAX4426/MAX4427/MAX4428 maximum on resistance, and  $I_{LOAD}$  is the MAX4426/MAX4427/MAX4428 load current.

For capacitive loads, the power dissipation is:

$$P = (C_{LOAD}) (V_{DD})^2 (FREQ)$$

where  $C_{LOAD}$  is the capacitive load,  $V_{DD}$  is the MAX4426/MAX4427/MAX4428 supply voltage, and FREQ is the toggle frequency.

# Dual High-Speed 1.5A MOSFET Drivers

MAX4426/MAX4427/MAX4428

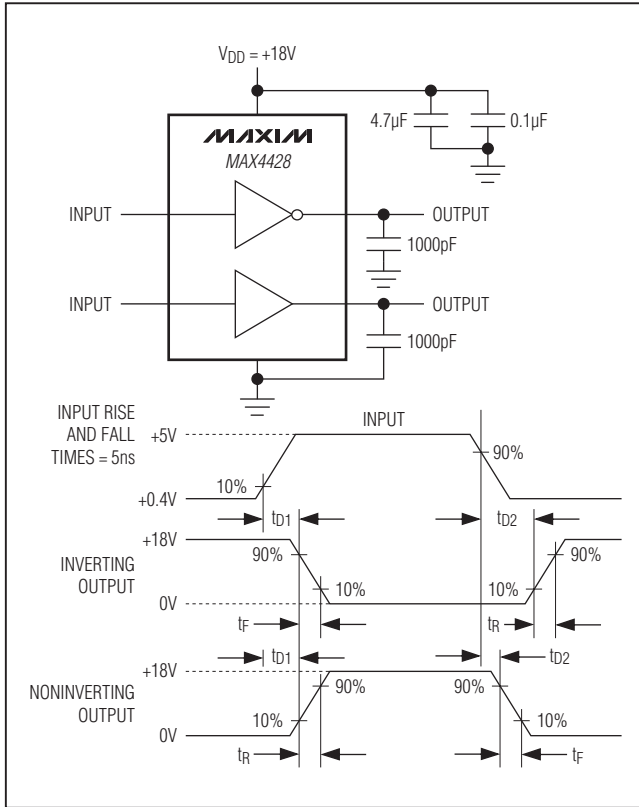


Figure 1. Inverting and Noninverting Test Circuit

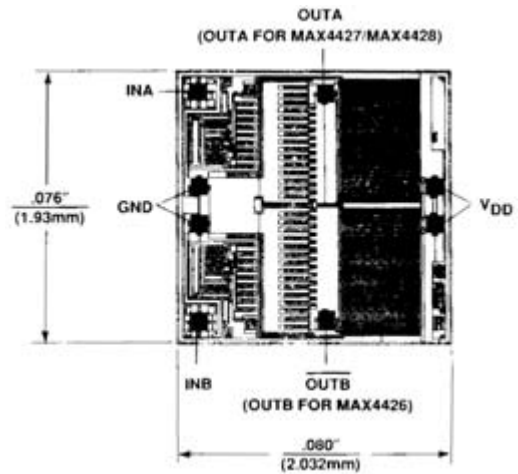
## Ordering Information (continued)

| PART       | TEMP RANGE      | PIN-PACKAGE   |
|------------|-----------------|---------------|
| MAX4427CPA | 0°C to +70°C    | 8 Plastic DIP |
| MAX4427CSA | 0°C to +70°C    | 8 SO          |
| MAX4427C/D | 0°C to +70°C    | Dice*         |
| MAX4427EPA | -40°C to +85°C  | 8 Plastic DIP |
| MAX4427ESA | -40°C to +85°C  | 8 SO          |
| MAX4427EJA | -40°C to +85°C  | 8 CERDIP      |
| MAX4427MJA | -55°C to +125°C | 8 CERDIP**    |
| MAX4428CPA | 0°C to +70°C    | 8 Plastic DIP |
| MAX4428CSA | 0°C to +70°C    | 8 SO          |
| MAX4428C/D | 0°C to +70°C    | Dice*         |
| MAX4428EPA | -40°C to +85°C  | 8 Plastic DIP |
| MAX4428ESA | -40°C to +85°C  | 8 SO          |
| MAX4428EJA | -40°C to +85°C  | 8 CERDIP      |
| MAX4428MJA | -55°C to +125°C | 8 CERDIP**    |

\*Dice are tested at  $T_A = +25^\circ\text{C}$ .

\*\*Contact factory for availability and processing to MIL-STD-883.

## Chip Topography



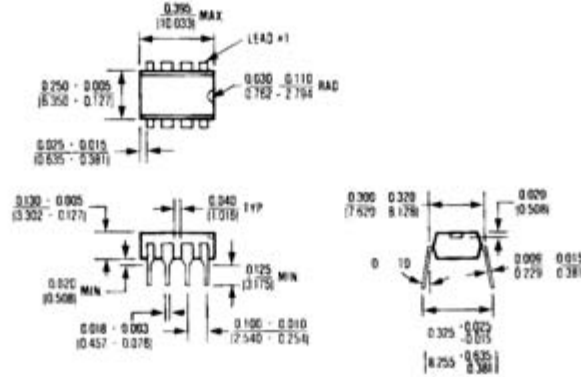
SUBSTRATE CONNECTED TO  $V_{DD}$ ;  
TRANSISTOR COUNT: 26.

MAX4427/MAX4428

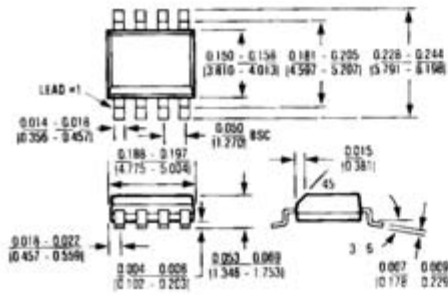
# Dual High-Speed 1.5A MOSFET Drivers

## Package Information

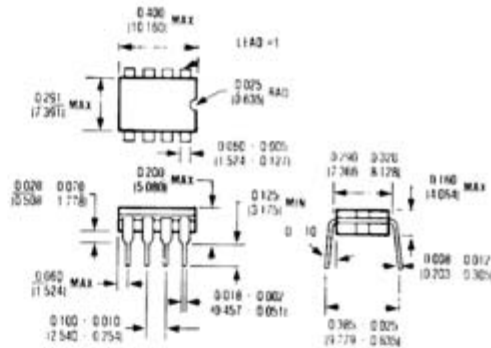
(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to [www.maxim-ic.com/packages](http://www.maxim-ic.com/packages).)



**8 Lead Plastic DIP**  
 $\theta_{JA} = 120\text{ C/W}$   
 $\theta_{JC} = 70\text{ C/W}$



**8 Lead Small Outline**  
 $\theta_{JA} = 170\text{ C/W}$   
 $\theta_{JC} = 80\text{ C/W}$



**8 Lead Cerdip**  
 $\theta_{JA} = 125\text{ C/W}$   
 $\theta_{JC} = 55\text{ C/W}$

# Dual High-Speed 1.5A MOSFET Drivers

## Revision History

| REVISION NUMBER | REVISION DATE | DESCRIPTION  | PAGES CHANGED |
|-----------------|---------------|--|---------------|
| 2               | 6/06          | To clarify and illuminate an input logic level restriction | —             |

MAX4426/MAX4427/MAX4428

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